



Pre-Production Datasheet v3.0

DC-20 GHz MMIC SPST ABSORPTIVE SWITCH

FEATURES:

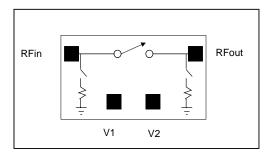
- Low insertion loss: 2.2 dB at 20 GHz
- High isolation: 50 dB at 20 GHz
- Absorptive input and output in off-state
- Excellent low control voltage performance
- Available in die form

GENERAL DESCRIPTION:

The FMS2029 is a low loss high isolation broadband single-pole-single-throw Gallium Arsenide switch, designed on the FL05 0.5μ m switch process from Filtronic. It offers absorptive properties from both ports (50 Ohms terminations).

This process technology offers leading-edge performance optimised for switch applications. The FMS2029 is developed for the broadband communications, instrumentation and electronic warfare markets.

FUNCTIONAL SCHEMATIC:



TYPICAL APPLICATIONS:

- Broadband communications
- Test Instrumentation
- Fibre Optics
- Electronic warfare (ECM, ESM)

ELECTRICAL SPECIFICATIONS (SMALL-SIGNAL UNLESS OTHERWISE STATED):

PARAMETER	Conditions	Min	Typ	MAX	UNITS
	DC	-1	-0.85	-	dB
	5 GHz	-1.35	-1	-	dB
Insertion Loss	10 GHz	-1.65	-1.4	-	dB
	15 GHz	-2	-1.7	-	dB
	20 GHz	-2.55	-2.3	-	dB
Isolation	DC-20 GHz	-	-60	-45	dB
Input Return Loss (ON state)	DC-20 GHz	_	-20	-17	dB
Output Return Loss (ON state)	DC-20 GHz	-	-20	-17	dB
Input Return Loss (OFF state)	DC-20 GHz	-	-12	-10	dB
Output Return Loss (OFF state)	DC-20 GHz	_	-12	-10	dB
	2 GHz	24.5	26.7	-	dBm
P1dB	10 GHz	23.5	25.2	-	dBm
	20 GHz	20.5	22.5	-	dBm
	10% to 90% RF	-	17	-	ns
Switching speed	90% to 10% RF	-	42	-	ns
	50% DC to 90% RF	-	27	-	ns
	50% DC to 10% RF	-	53	-	ns

Note 1: T_{AMBIENT} = 25°C, Vctrl = 0V/-5V

Note 2 : Specifications based on on-wafer measurements

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Tel: +44 (0) 1325 301111

Fax: +44 (0) 1325 306177 Email: sales@filcs.com

Website: www.filtronic.com



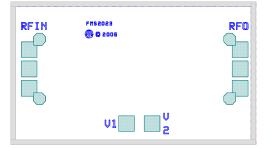
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ABSOLUTE MAXIMUM RATINGS:

PARAMETER	SYMBOL	Absolute Maximum
Max Input Power	Pin	+27dBm
Operating Temp	Toper	-40°C to +85°C
Storage Temp	Tstor	-55°C to +150°C

Note: Exceeding any one of these absolute maximum ratings may cause permanent damage to the device.

PAD LAYOUT:



TRUTH TABLE:

Contr	OL LINE	RF PATH
V1	V2	RFIN-RFO
-5V	0V	On (Low Loss)
0V	-5V	Off (Isolation)

Note: -5V \pm 0.2V; 0V \pm 0.2V

Pad Name	DESCRIPTION	Pin Coordinates (µm)
RFIN	RFIN	141,587
RFO	RFOUT	1789,587
V1	V1	901,161
V2	V2	1101,161

Note: Co-ordinates are referenced from the bottom left hand corner of the die to the centre of bond pad opening

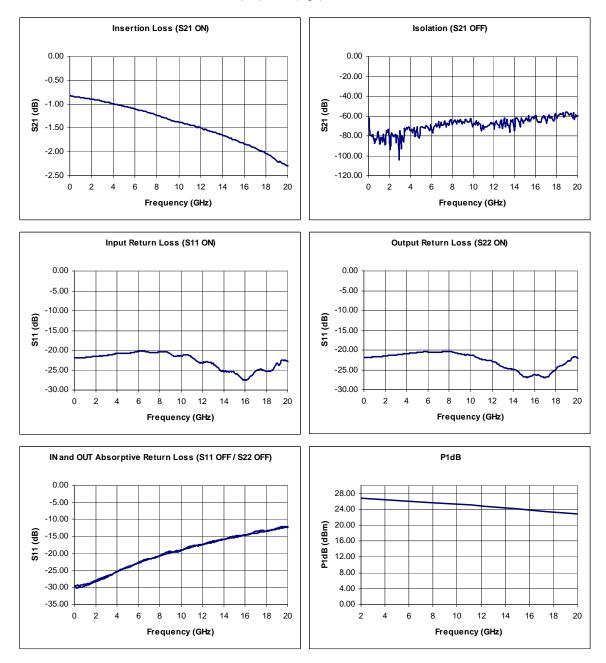
DIE SIZE (µm)	DIE THICKNESS (µm)	MIN. BOND PAD PITCH (µm)	MIN. BOND PAD OPENING (μm x μm)
1910 x 1110	100	150	116 x 116





TYPICAL PERFORMANCE FOR ON-WAFER MEASUREMENTS:

Note: Measurement Conditions V_{CTRL}= -5V (low) & 0V (high), T_{AMBIENT} = 25° C unless otherwise stated



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TYPICAL PERFORMANCE FOR ON-WAFER MEASUREMENTS OVER TEMPERATURE: Note: Measurement Conditions V_{CTRL}= -5V (low) & 0V (high)

--- $T_{COLD} = -40^{\circ}C$ ------ $T_{HOT} = +85^{\circ}C$ $-T_{AMBIENT} = 25^{\circ}C$ Insertion Loss (S21 ON) Isolation (S21 OFF) 0.00 0.00 -20.00 -0.50 -40.00 S21 (dB) -1.00 (Bb -60.00 **ស៊** -1.50 -80.00 -2.00 -100.00 -120.00 -2.50 0 2 4 6 8 10 12 14 16 18 20 0 2 4 6 8 10 12 14 16 18 20 Frequency (GHz) Frequency (GHz) Input Return Loss (S11 ON) Output Return Loss (S22 ON) 0.00 0.00 -5.00 -5.00 -10.00 -10.00 S11 (dB) S22 (dB) -15.00 -15.00 -20.00 -20.00 -25.00 -25.00 -30.00 -30.00 0 2 4 6 8 10 12 14 16 18 0 2 4 6 8 10 12 14 16 18 20 20 Frequency (GHz) Frequency (GHz) Absorptive Output Return Loss (S22 OFF) P1dB 0.00 28.00 -5.00 24.00 -10.00 20.00 P1dB (dBm) æ -15.00 16.00 -20.00 12.00 -25.00 8.00 -30.00 4.00 0.00 -35.00 6 10 16 18 20 0 2 4 6 8 10 12 14 16 18 20 2 4 8 12 14 Frequency (GHz) Frequency (GHz)

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PREFERRED ASSEMBLY INSTRUCTIONS:

GaAs devices are fragile and should be handled with great care. Specially designed collets should be used where possible.

The back of the die is metallised and the recommended mounting method is by the use of conductive epoxy. Epoxy should be applied to the attachment surface uniformly and sparingly to avoid encroachment of epoxy on to the top face of the die and ideally should not exceed half the chip height. For automated dispense Ablestick LMISR4 is recommended and for manual dispense Ablestick 84-1 LMI or 84-1 LMIT are recommended. These should be cured at a temperature of 150°C for one hour in an oven especially set aside for epoxy curing only. If possible the curing oven should be flushed with dry nitrogen. Eutectic die attach is not recommended.

This part has gold (Au) bond pads requiring the use of gold (99.99% pure) bondwire. It is recommended that 25.4µm diameter gold wire be used. Thermosonic ball bonding is preferred. A nominal stage temperature of 150°C and a bonding force of 40g has been shown to give effective results for 25µm wire. Ultrasonic energy shall be kept to a minimum. For this bonding technique, stage temperature should not be raised above 200°C and bond force should not be raised above 60g. Thermosonic wedge bonding and thermocompression wedge bonding can also be used to achieve good wire bonds.

Bonds should be made from the die first and then to the mounting substrate or package. The physical length of the bondwires should be minimised especially when making RF or ground connections.

HANDLING PRECAUTIONS:

To avoid damage to the devices care should be exercised during handling.



Proper Electrostatic Discharge (ESD) precautions should be observed at all stages of storage, handling, assembly, and testing. These devices should be treated as Class 1A (250-500 V) as defined in JEDEC Standard No. 22-A114. Further information on ESD control measures can be found in MIL-STD-1686 and MIL-HDBK-263.

APPLICATION NOTES & DESIGN DATA:

Application Notes and design data including Sparameters are available on request.

DISCLAIMERS:

This product is not designed for use in any space based or life sustaining/supporting equipment.

ORDERING INFORMATION:

PART NUMBER	DESCRIPTION
FMS2029-000-WP	Die in Waffle-pack (Gel-pak available on request)

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